TOSHIBA DIODE SILICON EPITAXIAL SCHOTTKY BARRIER TYPE

155319

LOW VOLTAGE HIGH SPEED SWITCHING.

• Low Forward Voltage: V_{F(3)}=0.54V (Typ.)

• Low Reverse Current : I_R=5μA (Max.)

• Small Package : SC-61

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Maximum (Peak) Reverse Voltage	v_{RM}	45	V	
Reverse Voltage	$V_{\mathbf{R}}$	40	V	
Maximum (Peak) Forward Current	I_{FM}	300 (*)	mA	
Average Forward Current	IO	100 (*)	mA	
Power Dissipation	P	150 (*)	mW	
Junction Temperature	T_{j}	125	$^{\circ}\mathrm{C}$	
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	$^{\circ}\mathrm{C}$	

Unit in mm

2.9-0.3

0.55

0.55

1.50-0.15

1. CATHODE 1
2. CATHODE 2
3. ANODE 2
4. ANODE 1

JEDEC

EIAJ

SC-61

TOSHIBA

2-3J1A

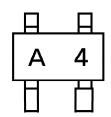
Weight: 0.013g

(*) Unit Rating. Total Rating=Unit Rating×1.5.

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage	V _{F(1)}	I _F =1mA	_	0.28		
	$V_{F(2)}$	$I_{ m F} = 10 { m mA}$		0.36		V
	$V_{F(3)}$	$I_{ m F}$ = 100mA		0.54	0.60	
Reverse Current	$I_{ m R}$	$V_R = 40V$		_	5	μ A
Total Capacitance	${ m C_T}$	$V_R=0$, f=1MHz	_	18	25	pF

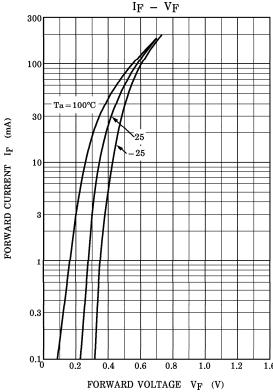
MARKING

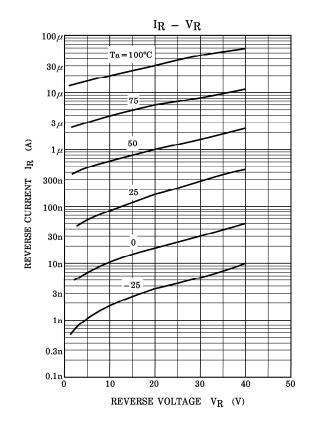


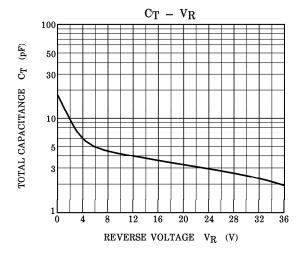
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300 100







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